

CTVS – Ceramic transient voltage suppressors

SMD multilayer varistors (MLVs), surge protection series

Series/Type:

Date: December 2019

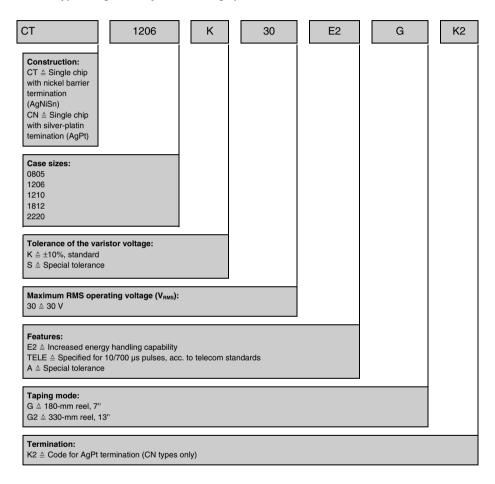
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Surge protection series

<u>SMD</u>

EPCOS type designation system for surge protection series





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Description

The surge protection series comprises a range of multilayer varistors for protection against severe transient overvoltage and high surge currents, such as 8/20 μ s pulses with peak currents up to 6000 A and 10/700 μ s pulses up to 45 A.

Features

- High energy absorption capability
- High surge load capability acc. to IEC 61000-4-5
- Reliable ESD protection up to 30 kV acc. to IEC 61000-4-2, level 4
- High surge voltage capability up to 2 kV for 10/700 µs acc. to IEC 61000-4-5 (types with V_{RMS,max} ≤ 60 V)
- UL approval to UL 1449 (file number E481997)
- Bidirectional protection
- Low leakage current
- Long-term ESD stability
- RoHS-compatible, lead-free
- PSpice simulation modesl available

Applications

- Industrial applications
- Building safety and security applications
- Power supplies
- Control and measurement equipment
- Hard disk drives

Design

- Multilayer technology
- Flammability rating better than UL 94 V-0
- Termination (see "Soldering directions"):
 - CT types with nickel barrier terminations (AgNiSn), recommended for lead-free soldering, and compatible with tin/lead solder
 - CN types with silver-platin termination (AgPt) for reflow and wave soldering with solder on tin/lead basis or lead-free with a silver containing solder

V/I characteristics and derating curves

V/l and derating curves are attached to the data sheet. The curves are sorted by V_{RMS} and then by case size, which is included in the type designation.

Single chip

Internal circuit



MLV0006-H

Available case sizes:

EIA	Metric
0805	2012
1206	3216
1210	3225
1812	4532
2220	5750



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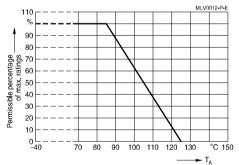
General technical data

Maximum RMS operating voltage		$V_{\text{RMS,max}}$	30 115	V
Maximum DC operating voltage		V _{DC,max}	38 150	V
Maximum surge current	(8/20 μs)	I _{surge,max}	40 6000	Α
Maximum surge current	(10/700 µs)	I _{surge,max}	45	Α
Maximum clamping voltage		$V_{\text{clamp,max}}$	77 360	V
Operating temperature	(8/20 μs surge ratings)	T _{op}	-55/+125	°C
Operating temperature	(10/700 µs surge ratings)	T _{op}	-40/+85	°C
Storage temperature	(8/20 μs surge ratings)	LCT/UCT	-55/+150	°C
Storage temperature	(10/700 µs surge ratings)	LCT/UCT	-40/+125	°C
Response time		t _{resp}	< 0.5	ns

Temperature derating

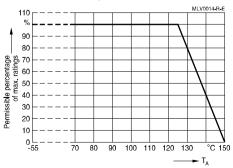
Climatic category:

-40/+85 °C for chip size 1812 (dedicated telecom types: CT1812S60AG2, CT1812K75TELEG2, CT1812S95 AG2, CT1812K115TELEG2)



Climatic category:

-55/+125 °C for chip sizes 0805, 1206, 1210, 1812, and 2220



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Electrical specifications and ordering codes

Maximum ratings (T_{op,max})

Туре	Ordering code	$V_{\text{RMS,max}}$	$V_{\text{DC,max}}$	I _{surge,max}	I _{surge,max}	W _{max}	$\mathbf{P}_{\text{diss,max}}$
				(8/20 µs)	(10/700 µs)	(2 ms)	(2 ms)
		V	V	A	А	mJ	mW
High surge protection t	High surge protection types, 8/20 μ s surge rating, T _{op,max} = +125 °C						
CT2220K30E2G	B72540T6300K062	30	38	5000	-	15000	20
CN2220K30E2GK2	B72542V6300K062	30	38	6000	-	15000	20
CN2220K50E2GK2	B72542V6500K062	50	65	4500	-	15000	20
CN2220S50E2GK2	B72542V6500S162	50	63	4500	-	15000	20
CT2220K50E2G	B72540T6500K062	50	65	4500	-	15000	20
CT2220S50E3G	B72540T6500S162	50	63	4500	-	15000	20
CN2220K60E2GK2	B72542V6600K062	60	85	4500	-	15000	20
Surge protection types	, 8/20 µs surge rating	, T _{op,max} =	+125 °	0			
CT0805K30G	B72510T0300K062	30	38	80	-	300	5
CT1206K30G	B72520T0300K062	30	38	200	-	1100	8
CT1210K30G	B72530T0300K062	30	38	300	-	2000	10
CT1812K30G	B72580T0300K062	30	38	800	-	4200	15
CT2220K30G	B72540T0300K062	30	38	1200	-	12000	20
CT0805K35G	B72510T0350K062	35	45	80	-	300	5
CT1206K35G	B72520T0350K062	35	45	100	-	400	8
CT1210K35G	B72530T0350K062	35	45	250	-	2000	10
CT1812K35G	B72580T0350K062	35	45	500	-	4000	15
CT1206K40G	B72520T0400K062	40	56	100	-	500	8
CT1210K40G	B72530T0400K062	40	56	250	-	2300	10
CT1812K40G	B72580T0400K062	40	56	500	-	4800	15
CT2220K40G	B72540T0400K062	40	56	1000	-	9000	20
CT1206K50G	B72520T0500K062	50	65	100	-	600	8
CT1210K50G	B72530T0500K062	50	65	200	-	1600	10
CT1812K50G	B72580T0500K062	50	65	400	-	4500	15
CT2220K50G	B72540T0500K062	50	65	800	-	5600	20
CT1210K50E2G	B72530T6500K062	50	65	1200	-	3000	10
CT1206K60G	B72520T0600K062	60	85	100	-	700	8
CT1210K60G	B72530T0600K062	60	85	200	-	2000	10
CT1812K60G	B72580T0600K062	60	85	400	-	5800	15
CT2220K60G	B72540T0600K062	60	85	800	-	6800	20
CT1812K130G2	B72580T0131K072	130	170	250	-	3500	15
Telecom types, 10/700 μs surge rating, T _{op.max} = +85 °C							
CT1812S60AG2	B72580T0600S172	60	85	400	45	2200	15
CT1812K75TELEG2	B72580T6750K072	75	100	400	45	2500	15
CT1812S95AG2	B72580T0950S172	95	125	250	45	2800	15
CT1812K115TELEG2	B72580T6111K072	115	150	250	45	3200	15



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Characteristics (T_A = 25 $^{\circ}$ C)

Time	V _v	ΔV_{V}	V	1	C _{typ} ¹⁾	
Туре	(1 mA)	$\Delta \mathbf{v}_{V}$	V _{clamp,max}	I _{clamp}	(1 MHz, 1 V)	
	(TINA) V	0/	v	(8/20 µs)	· · /	
	•	%		A	pF	
High surge protection types, 8/20 μ s surge rating, T _{op,max} = +125 °C						
CT2220K30E2G	47	±10	77	10	10000	
CN2220K30E2GK2	47	±10	77	10	10000	
CN2220K50E2GK2	82	±10	135	10	3000	
CN2220S50E2GK2	77	±10	130	10	5000	
CT2220K50E2G	82	±10	135	10	3000	
CT2220S50E3G	77.5	±8.4	115	10	8800	
CN2220K60E2GK2	100	±10	165	10	3000	
Surge protection types, 8/20 µs	surge rating	$T_{op,max} = +12$	25 °C			
CT0805K30G	47	±10	77	1	200	
CT1206K30G	47	±10	77	1	500	
CT1210K30G	47	±10	77	2.5	1000	
CT1812K30G	47	±10	77	5	2000	
CT2220K30G	47	±10	77	10	4000	
CT0805K35G	56	±10	95	1	150	
CT1206K35G	56	±10	90	1	200	
CT1210K35G	56	±10	90	2.5	600	
CT1812K35G	56	±10	90	5	1200	
CT1206K40G	68	±10	110	1	250	
CT1210K40G	68	±10	110	2.5	500	
CT1812K40G	68	±10	110	5	1000	
CT2220K40G	68	±10	110	10	2000	
CT1206K50G	82	±10	135	1	120	
CT1210K50G	82	±10	135	2.5	250	
CT1812K50G	82	±10	135	5	500	
CT2220K50G	82	±10	135	10	1000	
CT1210K50E2G	82	±10	135	2.5	1200	
CT1206K60G	100	±10	165	1	100	
CT1210K60G	100	±10	165	2.5	200	
CT1812K60G	100	±10	165	5	400	
CT2220K60G	100	±10	165	10	800	
CT1812K130G2	205	±10	340	5	200	
Telecom types, 10/700 μs surge rating, T _{op,max} = +85 °C						
CT1812S60AG2	100	+19/-1	200	45	400	
CT1812K75TELEG2	120	±10	250	45	320	
CT1812S95AG2	165	±10	270	45	250	
CT1812K115TELEG2	180	±10	360	45	200	

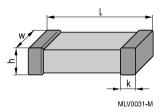
1) Measurement frequency: f = 1 MHz for C < 100 pF, f = 1 kHz for C \ge 100 pF



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Dimensional drawing



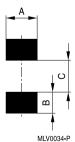
Dimensions in mm

Case size EIA / mm	I	w	h	k
0201 / 0603	0.6 ±0.03	$0.30\pm\!\!0.03$	0.33 max.	0.15 ±0.05
0402 / 1005	1.0 ±0.15	0.50 ±0.10	0.6 max.	0.10 0.30
0603 / 1608	1.6 ±0.15	0.80 ± 0.10	0.9 max.	0.10 0.40
0805 / 2012	2.0 ±0.20	1.25 ±0.15	1.4 max.	0.13 0.75
1206 / 3216	3.2 ± 0.30	1.60 ±0.20	1.7 max.	0.25 0.75
1210 / 3225	3.2 ± 0.30	2.50 ± 0.25	1.7 max.	0.25 0.75
1812 / 4532	4.5 ±0.40	3.20 ± 0.30	2.5 max.	0.25 1.00
2220 / 5750	5.7 ±0.40	$5.00\pm\!\!0.40$	2.5 max.1) 2)	0.25 1.00

 h_{max} = 3.0 mm for type CN2220K30E2GK2, CN2220K50E2GK2, CT2220K30E2G, CT2220K50E2G and CN2220S50E2GK2

2) $h_{max} = 3.3 \text{ mm}$ for type CT2220S50E3G and CN2220K60E2GK2

Recommended solder pad layout



Dimensions in mm

Case size	А	В	С
EIA / mm			
0201 / 0603	0.30	0.25	0.30
0402 / 1005	0.60	0.60	0.50
0603 / 1608	1.00	1.00	1.00
0805 / 2012	1.40	1.20	1.00
1206 / 3216	1.80	1.20	2.10
1210 / 3225	2.80	1.20	2.10
1812 / 4532	3.60	1.50	3.00
2220 / 5750	5.50	1.50	4.20



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Delivery mode

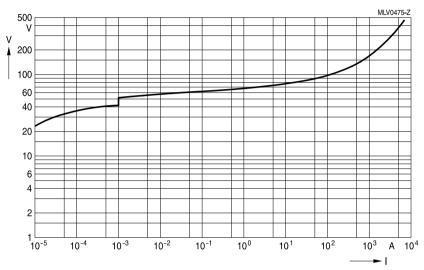
EIA case size	Taping	Reel size	Packing unit	Туре	Ordering code	
		mm	pcs.			
Single chip						
0805	Blister	180	3000	CT0805K30G	B72510T0300K062	
0805	Blister	180	3000	CT0805K35G	B72510T0350K062	
1206	Blister	180	2000	CT1206K30G	B72520T0300K062	
1206	Blister	180	2000	CT1206K35G	B72520T0350K062	
1206	Blister	180	2000	CT1206K40G	B72520T0400K062	
1206	Blister	180	2000	CT1206K50G	B72520T0500K062	
1206	Blister	180	2000	CT1206K60G	B72520T0600K062	
1210	Blister	180	2000	CT1210K30G	B72530T0300K062	
1210	Blister	180	2000	CT1210K35G	B72530T0350K062	
1210	Blister	180	2000	CT1210K40G	B72530T0400K062	
1210	Blister	180	2000	CT1210K50E2G	B72530T6500K062	
1210	Blister	180	2000	CT1210K50G	B72530T0500K062	
1210	Blister	180	2000	CT1210K60G	B72530T0600K062	
1812	Blister	180	1000	CT1812K30G	B72580T0300K062	
1812	Blister	180	1000	CT1812K35G	B72580T0350K062	
1812	Blister	180	1000	CT1812K40G	B72580T0400K062	
1812	Blister	180	1000	CT1812K50G	B72580T0500K062	
1812	Blister	180	1000	CT1812K60G	B72580T0600K062	
1812	Blister	180	3000	CT1812K130G2	B72580T0131K072	
1812	Blister	330	3000	CT1812K115TELEG2	B72580T6111K072	
1812	Blister	330	3000	CT1812S95AG2	B72580T0950S172	
1812	Blister	330	4000	CT1812K75TELEG2	B72580T6750K072	
1812	Blister	330	4000	CT1812S60AG2	B72580T0600S172	
2220	Blister	180	500	CT2220S50E3G	B72540T6500S162	
2220	Blister	180	600	CN2220K30E2GK2	B72542V6300K062	
2220	Blister	180	600	CN2220K50E2GK2	B72542V6500K062	
2220	Blister	180	600	CN2220K60E2GK2	B72542V6600K062	
2220	Blister	180	600	CN2220S50E2GK2	B72542V6500S162	
2220	Blister	180	600	CT2220K30E2G	B72540T6300K062	
2220	Blister	180	600	CT2220K50E2G	B72540T6500K062	
2220	Blister	180	1000	CT2220K30G	B72540T0300K062	
2220	Blister	180	1000	CT2220K40G	B72540T0400K062	
2220	Blister	180	1000	CT2220K50G	B72540T0500K062	
2220	Blister	180	1000	CT2220K60G	B72540T0600K062	



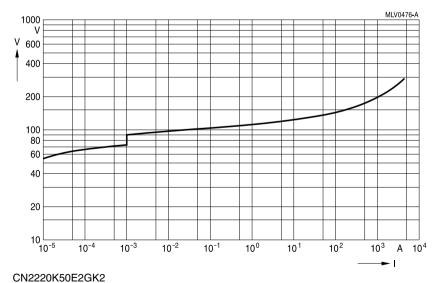
Surge protection series

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CN2220K30E2GK2

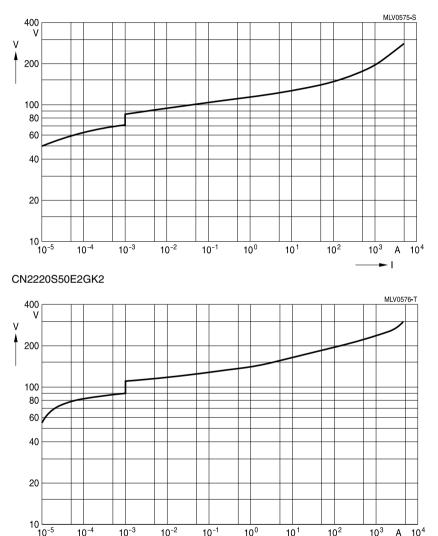




Surge protection series

<u>SMD</u>

V/I characteristics for high surge protection types



CN2220K60E2GK2

10⁻⁴

10⁻³

10⁻²

10⁻¹

10⁰

10¹

10²

10³

► |

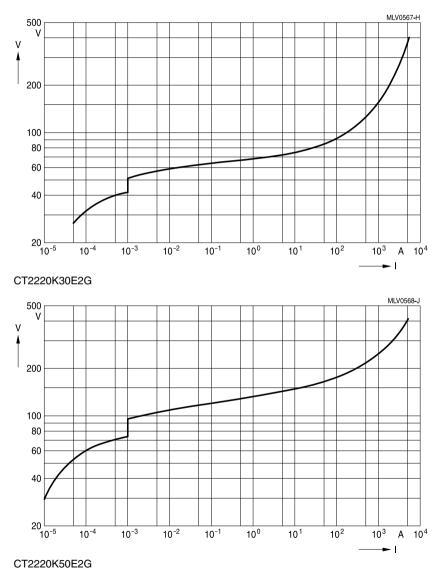
A 10⁴



Surge protection series

<u>SMD</u>

V/I characteristics for high surge protection types

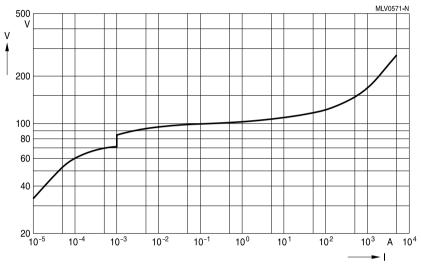




Surge protection series

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V/I characteristics for high surge protection types



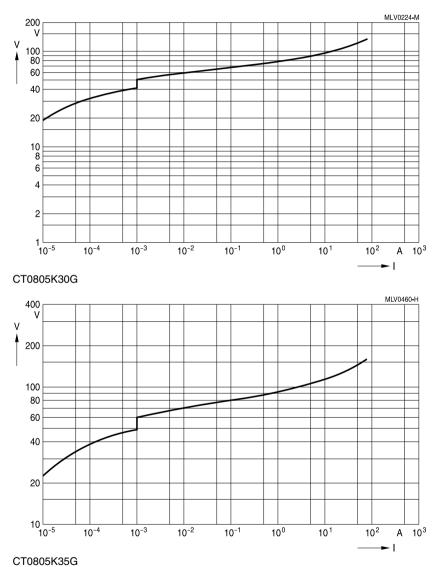
CT2220S50E3G



Surge protection series

SMD

V/I characteristics for surge protection types

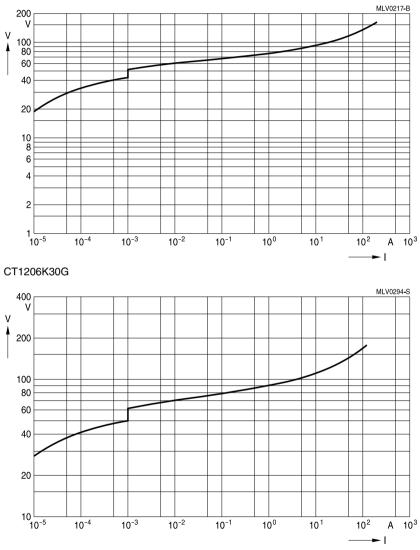




Surge protection series

<u>SMD</u>

V/I characteristics for surge protection types



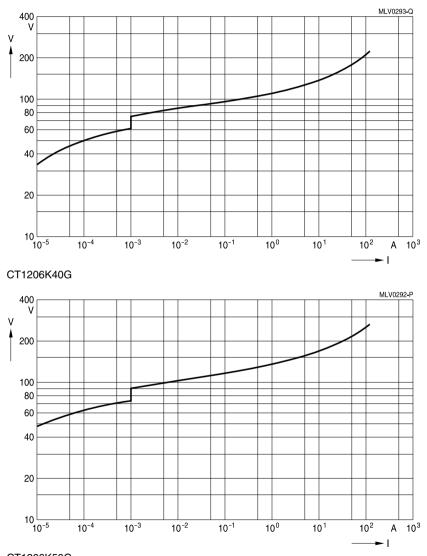
CT1206K35G



Surge protection series

<u>SMD</u>

V/I characteristics for surge protection types

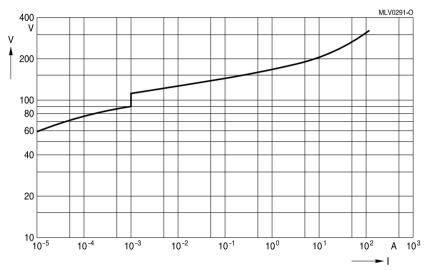




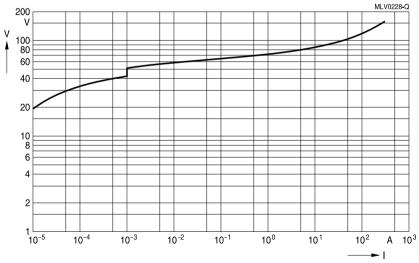
Surge protection series

<u>SMD</u>

V/I characteristics for surge protection types



CT1206K60G



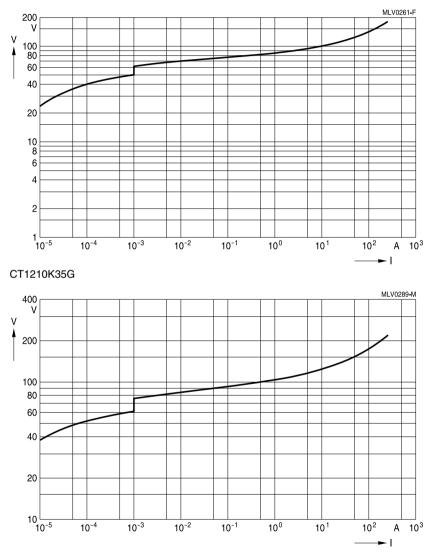
CT1210K30G



Surge protection series

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V/I characteristics for surge protection types



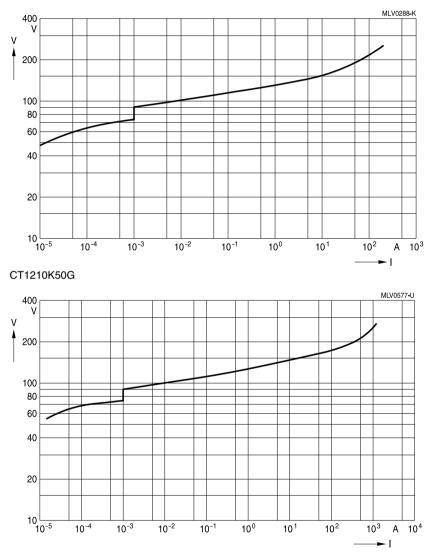
CT1210K40G



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V/I characteristics for surge protection types



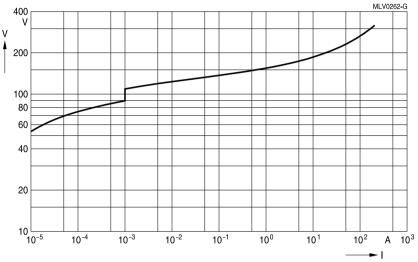
CT1210K50E2G



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V/I characteristics for surge protection types



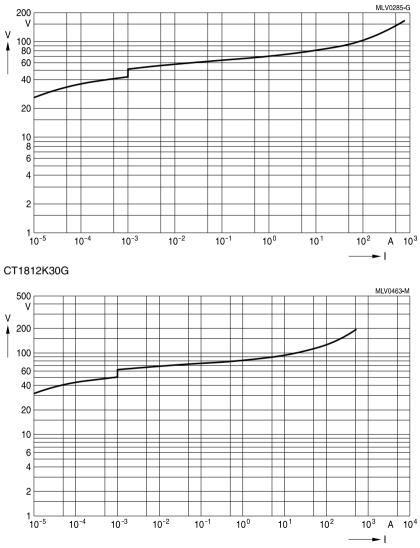
CT1210K60G



Surge protection series

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V/I characteristics for surge protection types



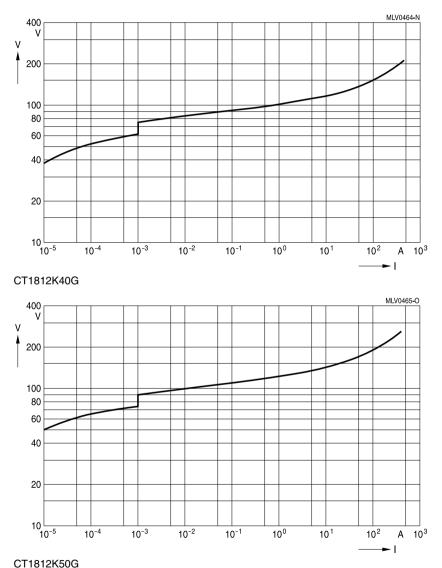
CT1812K35G



Surge protection series

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V/I characteristics for surge protection types

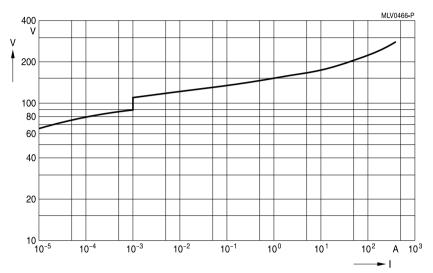




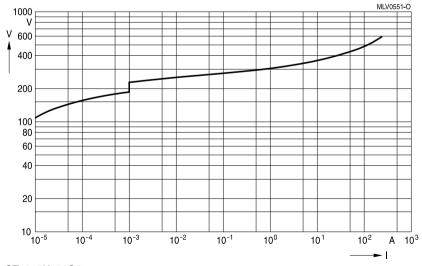
Surge protection series

<u>SMD</u>

V/I characteristics for surge protection types



CT1812K60G



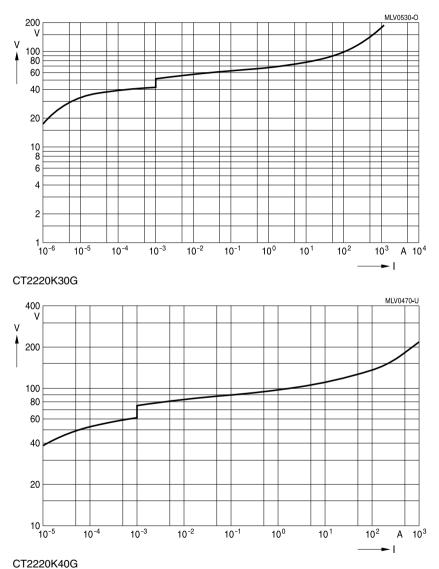
CT1812K130G2



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V/I characteristics for surge protection types

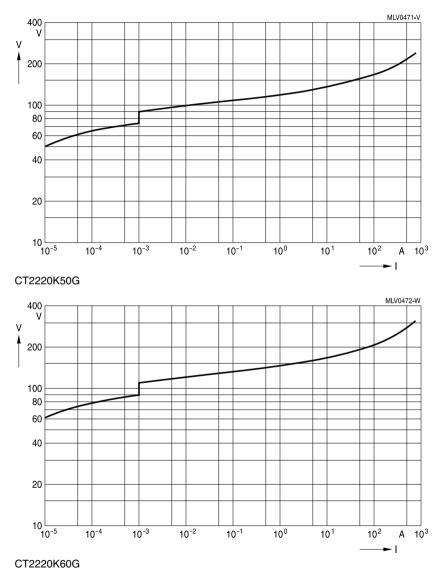




Surge protection series

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V/I characteristics for surge protection types

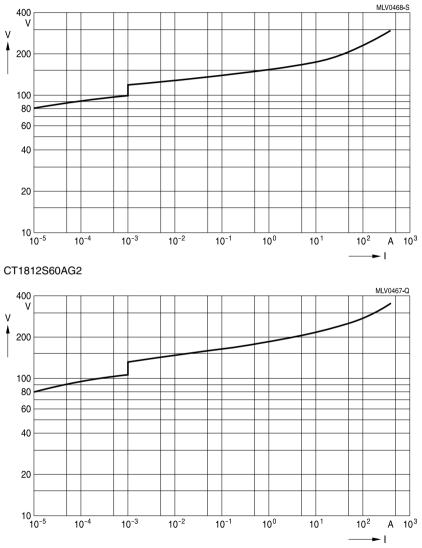




Surge protection series

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V/I characteristics for telecom types



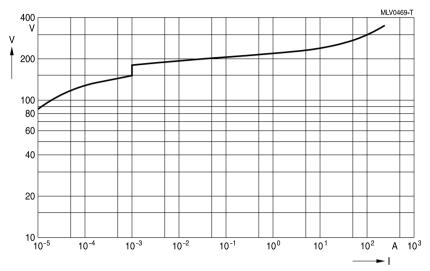
CT1812K75TELEG2



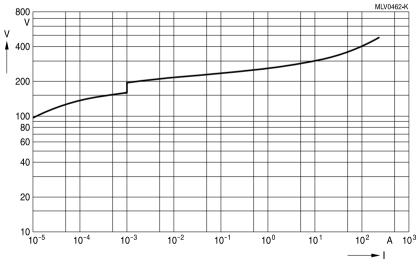
Surge protection series

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V/I characteristics for telecom types



CT1812S95AG2



CT1812K115TELEG2



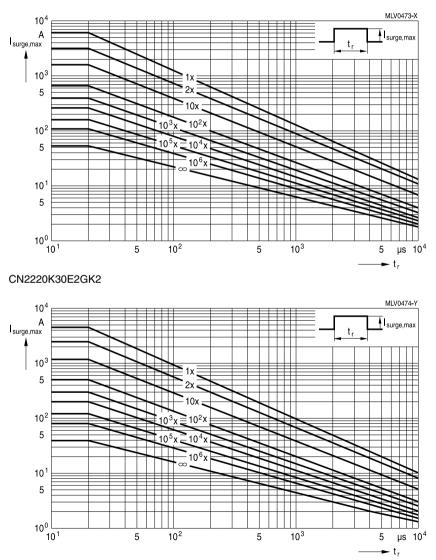
Surge protection series

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Derating curves for high surge protection types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CN2220K50E2GK2, CT2220K50E2G



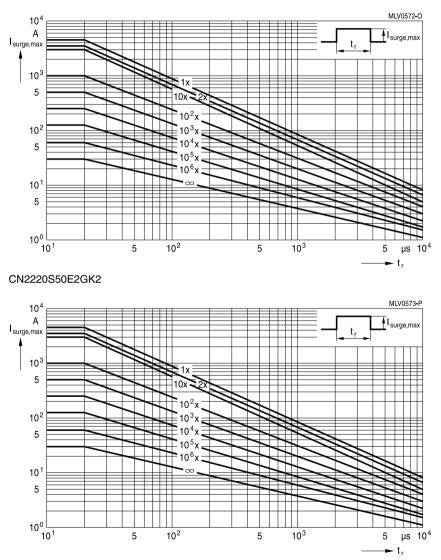
Surge protection series

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Derating curves for high surge protection types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CN2220K60E2GK2



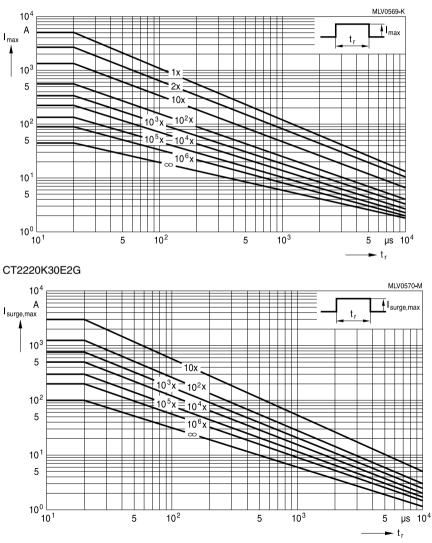
Surge protection series

<u>SMD</u>

Derating curves for high surge protection types

Maximum surge current $I_{surge,max} = f(t_r, pulse train)$

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT2220S50E3G



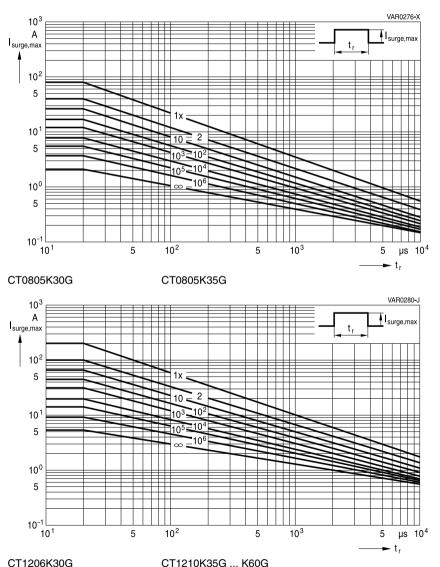
Surge protection series

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Derating curves for surge protection types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1





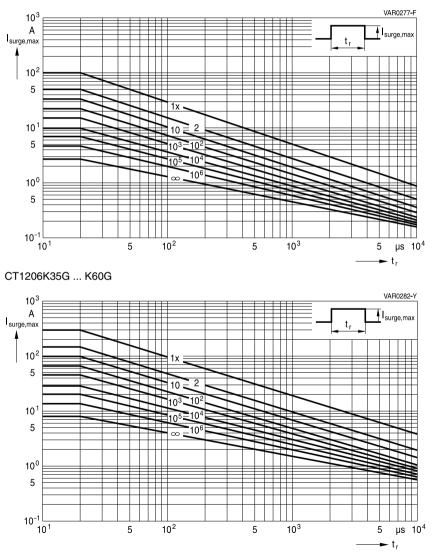
Surge protection series

<u>SMD</u>

Derating curves for surge protection types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT1210K30G



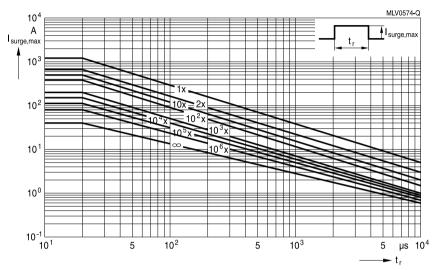
Surge protection series

<u>SMD</u>

Derating curves for surge protection types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT1210K50E2G



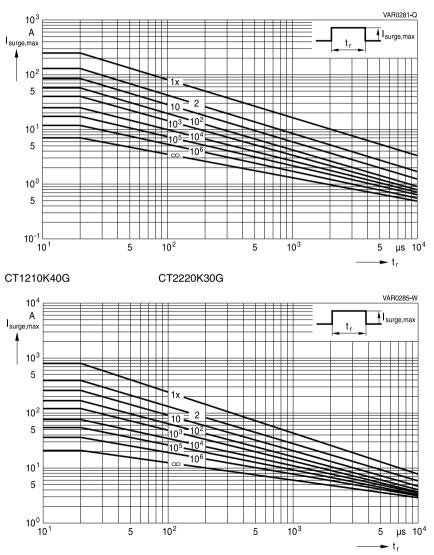
Surge protection series

<u>SMD</u>

Derating curves for surge protection types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT1812K30G



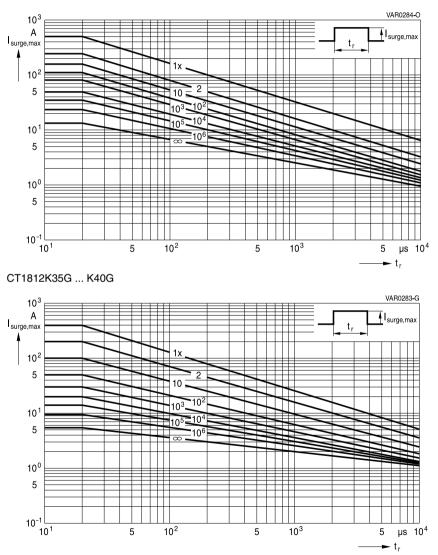
Surge protection series

<u>SMD</u>

Derating curves for surge protection types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT1812K50G ... K60G



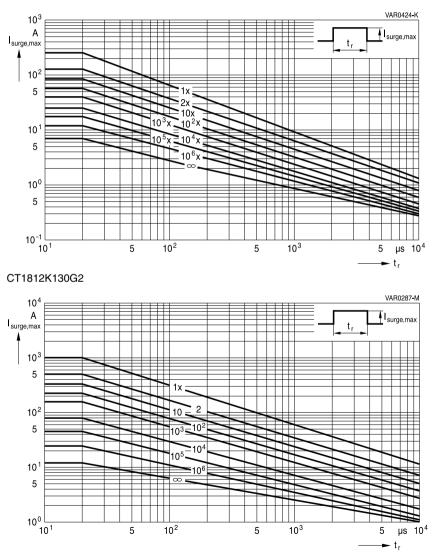
Surge protection series

<u>SMD</u>

Derating curves for surge protection types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT2220K40G



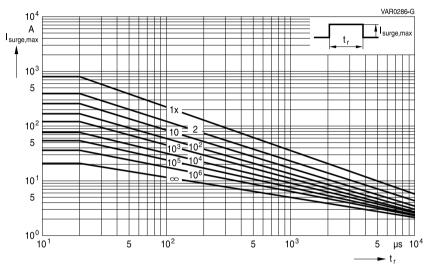
Surge protection series

<u>SMD</u>

Derating curves for surge protection types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



CT2220K50G ... K60G



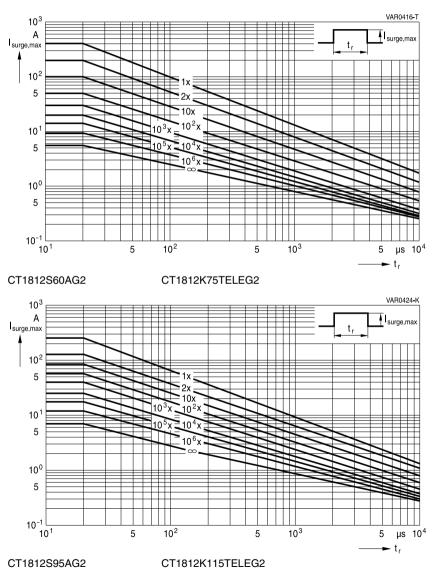
Surge protection series

<u>SMD</u>

Derating curves for telecom types

Maximum surge current I_{surge,max} = f (t_r, pulse train)

For explanation of the derating curves refer to "General technical information", chapter 2.7.1



Please read *Cautions and warnings* and *Important notes* at the end of this document.



Surge protection series

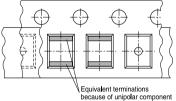
<u>SMD</u>

Taping and packing

- 1 Taping and packing for SMD components
- 1.1 Blister tape (taping to IEC 60286-3)

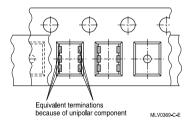
Part orientation in tape pocket for blister tape

For discrete chip, EIA case sizes 0603, 0805, 1206, 1210, 1812 and 2220



KKE0351-A-E

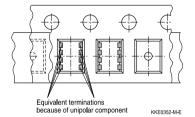
For arrays, EIA case sizes 0506 and 1012



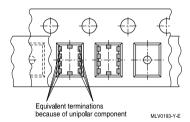
Additional taping information

Reel material Polystyrol (PS) Tape material Polystyrol (PS) or Polycarbonat (PC) or PVC Tape break force min. 10 N Top cover tape strength min. 10 N Top cover tape peel force 0.1 to 1.0 N for 8-mm tape and 0.1 to 1.3 N for 12-mm tape at a peel speed of 300 mm/min Angle between top cover tape and the direction of feed during peel off: 165° to 180° Tape peel angle Cavity play Each part rests in the cavity so that the angle between the part and cavity center line is no more than 20°

For array, EIA case size 0612



For filter array, EIA case size 0508





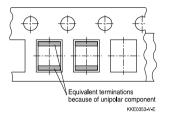
Surge protection series

<u>SMD</u>

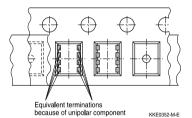
1.2 Cardboard tape (taping to IEC 60286-3)

Part orientation in tape pocket for cardboard tape

For discrete chip, EIA case sizes 0201, 0402, 0603 and 1003

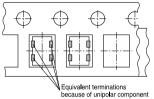


For array, EIA case size 0508



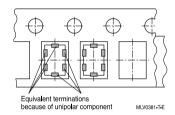
Additional taping information

For array, EIA case size 0405



KKE0354-4-E

For filter array, EIA case size 0405



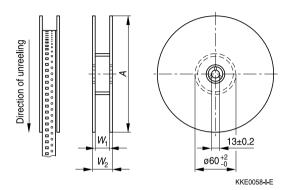
Reel material	Polystyrol (PS)
Tape material	Cardboard
Tape break force	min. 10 N
Top cover tape strength	min. 10 N
Top cover tape peel force	0.1 to 1.0 N at a peel speed of 300 mm/min
Tape peel angle	Angle between top cover tape and the direction of feed during peel off: 165° to 180°
Cavity play	Each part rests in the cavity so that the angle between the part and cavity center line is no more than 20°



Surge protection series

<u>SMD</u>

1.3 Reel packing

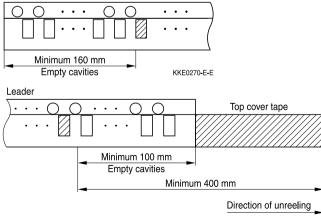


Dimensions in mm

	8-mm tape		12-mm tape	
	180-mm reel	330-mm reel	180-mm reel	330-mm reel
A	180 +0/-3	330 +0/-2.0	180 +0/-3	330 +0/-2.0
W ₁	8.4 +1.5/-0	8.4 +1.5/-0	12.4 +1.5/-0	12.4 +1.5/-0
W ₂	14.4 max.	14.4 max.	18.4 max.	18.4 max.

Leader, trailer

Trailer (tape end)



KKE0289-Q-E

Surge protection series

<u>SMD</u>

1.4 Packing units for discrete chip and array chip

	th			180 mm	300 mm
Case size	Chip thickness	Cardboard tape	Blister tape	Ø 180-mm reel	Ø 330-mm reel
inch/mm	th	W	W	pcs.	pcs.
0201/0603	0.33 mm	8 mm	-	15000	-
0402/1005	0.6 mm	8 mm	-	10000	50000
0405/1012	0.7 mm	8 mm	-	5000	-
0506/1216	0.5 mm	-	8 mm	4000	-
0508/1220	0.9 mm	8 mm	8 mm	4000	-
0603/1608	0.9 mm	8 mm	8 mm	4000	16000
0612/1632	0.7 mm	-	8 mm	3000	-
0805/2012	0.7 mm	-	8 mm	3000	-
	0.9 mm	-	8 mm	3000	12000
	1.3 mm	-	8 mm	3000	12000
1003/2508	0.9 mm	8 mm	-	4000	_
1012/2532	1.0 mm	-	8 mm	2000	-
1206/3216	0.9 mm	-	8 mm	3000	-
	1.3 mm	-	8 mm	3000	12000
	1.4 mm	-	8 mm	2000	8000
	1.6 mm	_	8 mm	2000	8000
1210/3225	0.9 mm	-	8 mm	3000	-
	1.3 mm	-	8 mm	3000	12000
	1.4 mm	-	8 mm	2000	8000
	1.6 mm	-	8 mm	2000	8000
1812/4532	1.3 mm	-	12 mm	1500	-
	1.4 mm	-	12 mm	1000	-
	1.6 mm	-	12 mm	1000	4000
	2.0 mm	-	12 mm	-	3000
	2.3 mm	-	12 mm	-	3000
2220/5750	1.3 mm	-	12 mm	1500	-
	1.4 mm	—	12 mm	1000	-
	1.6 mm	—	12 mm	1000	—
	2.0 mm	—	12 mm	-	3000
	2.3 mm	—	12 mm	-	3000
	2.7 mm	—	12 mm	600	—
	3.0 mm	-	12 mm	600	—



Surge protection series

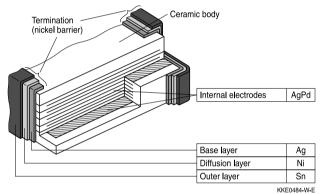
<u>SMD</u>

Soldering directions

1 Terminations and soldering methods

1.1 Nickel barrier termination

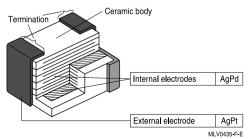
The nickel barrier layer of the silver/nickel/tin termination prevents leaching of the silver base metallization layer. This allows great flexibility in the selection of soldering parameters. The tin prevents the nickel layer from oxidizing and thus ensures better wetting by the solder. The nickel barrier termination is suitable for lead-free soldering, as well as for other commonly-used soldering methods.



Multilayer CTVS: Structure of nickel barrier termination

1.2 Silver-platinum termination

Silver-platinum terminations are mainly used for the large EIA case sizes 1812 and 2220. The silver-platinum termination is approved for reflow soldering, SnPb soldering and lead-free soldering with a silver containing solder paste. In case of SnPb soldering, a solder paste Sn62Pb36Ag2 is recommended. For lead-free reflow soldering, a solder paste SAC, e.g. Sn95.5Ag3.8Cu0.7, is recommended.



Multilayer varistor: Structure of silver-platinum termination



Surge protection series

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1.3 Silver-palladium termination

Silver-palladium terminations are designed for the use of conductive adhesivs. Lead-free reflow soldering does not form a proper solder joint. In general reflow or wave soldering is not recommended.

1.4 Tinned iron wire

All SHCV types with tinned terminations are suitable for lead-free and SnPb soldering.



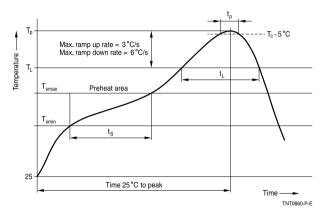
Surge protection series

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2 Recommended soldering temperature profiles

2.1 Reflow soldering temperature profile

Temperature ranges for reflow soldering acc. to IEC 60068-2-58 recommendations.



Profile feature		Sn-Pb eutectic assembly	Pb-free assembly
Preheat and soak			
- Temperature min	T_{smin}	100 °C	150 °C
- Temperature max	T _{smax}	150 °C	200 °C
- Time	$t_{\mbox{\tiny smin}}$ to $t_{\mbox{\tiny smax}}$	60 120 s	60 120 s
Average ramp-up rate	T_{smax} to T_{p}	3 °C/ s max.	3 °C/ s max.
Liquidous temperature	TL	183 °C	217 °C
Time at liquidous	tL	40 150 s	40 150 s
Peak package body temperature	T _p	215 °C 260 °C ¹⁾	235 °C 260 °C
Time above (T _P -5 °C)	t _p	10 40 s	10 40 s
Average ramp-down rate	T _p to T _{smax}	6 °C/ s max.	6 °C/ s max.
Time 25 °C to peak temperature		max. 8 minutes	max. 8 minutes

1) Depending on package thickness.

Notes: All temperatures refer to topside of the package, measured on the package body surface.

Number of reflow cycles: 3

Iron soldering should be avoided, hot air methods are recommended for repair purposes.

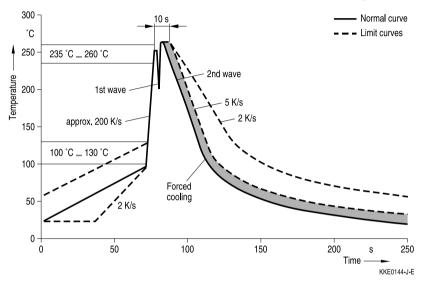


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2.2 Wave soldering temperature profile

Temperature characteristics at component terminal with dual-wave soldering



3 Solder joint profiles / solder quantity

3.1 Nickel barrier termination

If the meniscus height is too low, that means the solder quantity is too low, the solder joint may break, i.e. the component becomes detached from the joint. This problem is sometimes interpreted as leaching of the external terminations.

If the solder meniscus is too high, i.e. the solder quantity is too large, the vise effect may occur. As the solder cools down, the solder contracts in the direction of the component. If there is too much solder on the component, it has no leeway to evade the stress and may break, as in a vise.

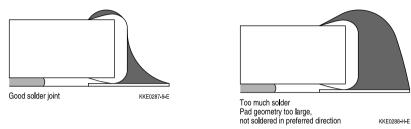
The figures below show good and poor solder joints for dual-wave and infrared soldering.



Surge protection series

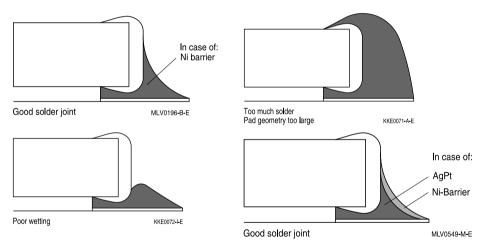
<u>SMD</u>

3.1.1 Solder joint profiles for nickel barrier termination - dual-wave soldering



Good and poor solder joints caused by amount of solder in dual-wave soldering.

3.1.2 Solder joint profiles for nickel barrier termination / silver-platinum termination - reflow soldering



Good and poor solder joints caused by amount of solder in reflow soldering.



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4 Solderability tests

Test	Standard	Test conditions	Test conditions	Criteria/ test results
Test	Standard	Sn-Pb soldering	Pb-free soldering	Chiena/ lest results
Wettability	IEC 60068-2-58	Immersion in 60/40 SnPb solder using non-activated flux at 215 \pm 3 °C for 3 \pm 0.3 s	Immersion in Sn96.5Ag3.0Cu0.5 solder using non- or low activated flux at 245 \pm 5 °C for 3 \pm 0.3 s	Covering of 95% of end termination, checked by visual inspection
Leaching resistance	IEC 60068-2-58	Immersion in 60/40 SnPb solder using mildly activated flux without preheating at 260 \pm 5 °C for 10 \pm 1 s	Immersion in Sn96.5Ag3.0Cu0.5 solder using non- or low activated flux without preheating at 255 ±5 °C for 10 ±1 s	No leaching of contacts
Thermal shock (solder shock)		Dip soldering at 300 °C/5 s	Dip soldering at 300 °C/5 s	No deterioration of electrical parameters. Capacitance change: $ \Delta C/C_0 \le 15\%$
Tests of resistance to soldering heat for SMDs		Immersion in 60/40 SnPb for 10 s at 260 °C	Immersion in Sn96.5Ag3.0Cu0.5 for 10 s at 260 °C	Change of varistor voltage: $ \Delta V/V (1 \text{ mA}) \le 5\%$
Tests of resistance to soldering heat for radial leaded components (SHCV)	IEC 60068-2-20	Immersion of leads in 60/40 SnPb for 10 s at 260 °C	Immersion of leads in Sn96.5Ag3.0Cu0.5 for 10 s at 260 °C	Change of varistor voltage: $ \Delta V/V (1 mA) \le 5\%$ Change of capacitance X7R: $\le -5/+10\%$



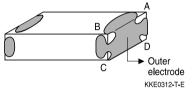
Surge protection series

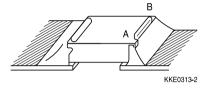
<u>SMD</u>

Note:

Leaching of the termination

Effective area at the termination might be lost if the soldering temperature and/or immersion time are not kept within the recommended conditions. Leaching of the outer electrode should not exceed 25% of the chip end area (full length of the edge A-B-C-D) and 25% of the length A-B, shown below as mounted on substrate.





As mounted on substrate

As a single chip

5 Notes for proper soldering

5.1 Preheating and cooling

According to IEC 60068-2-58. Please refer to section 2 of this chapter.

5.2 Repair/ rework

Manual soldering with a soldering iron must be avoided, hot-air methods are recommended for rework purposes.

5.3 Cleaning

All environmentally compatible agents are suitable for cleaning. Select the appropriate cleaning solution according to the type of flux used. The temperature difference between the components and cleaning liquid must not be greater than 100 °C. Ultrasonic cleaning should be carried out with the utmost caution. Too high ultrasonic power can impair the adhesive strength of the metal-lized surfaces.

5.4 Solder paste printing (reflow soldering)

An excessive application of solder paste results in too high a solder fillet, thus making the chip more susceptible to mechanical and thermal stress. Too little solder paste reduces the adhesive strength on the outer electrodes and thus weakens the bonding to the PCB. The solder should be applied smoothly to the end surface.



Surge protection series

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5.5 Selection of flux

Used flux should have less than or equal to 0.1 wt % of halogenated content, since flux residue after soldering could lead to corrosion of the termination and/or increased leakage current on the surface of the component. Strong acidic flux must not be used. The amount of flux applied should be carefully controlled, since an excess may generate flux gas, which in turn is detrimental to solderability.

5.6 Storage of CTVSs

Solderability is guaranteed for one year from date of delivery for multilayer varistors, CeraDiodes and ESD/EMI filters (half a year for chips with AgPt terminations) and two years for SHCV components, provided that components are stored in their original packages.

Storage temperature: -25 °C to +45 °C

Relative humidity: ≤75% annual average, ≤95% on 30 days a year

The solderability of the external electrodes may deteriorate if SMDs and leaded components are stored where they are exposed to high humidity, dust or harmful gas (hydrogen chloride, sulfurous acid gas or hydrogen sulfide).

Do not store SMDs and leaded components where they are exposed to heat or direct sunlight. Otherwise the packing material may be deformed or SMDs/ leaded components may stick together, causing problems during mounting.

After opening the factory seals, such as polyvinyl-sealed packages, it is recommended to use the SMDs or leaded components as soon as possible.

Solder CTVS components after shipment from TDK Electronics within the time specified:

CTVS with Ni barrier termination:	12 months
CTVS with AgPt termination:	6 months
SHCV (leaded components):	24 months

5.7 Placement of components on circuit board

Especially in the case of dual-wave soldering, it is of advantage to place the components on the board before soldering in that way that their two terminals do not enter the solder bath at different times.

Ideally, both terminals should be wetted simultaneously.



Surge protection series

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5.8 Soldering cautions

An excessively long soldering time or high soldering temperature results in leaching of the outer electrodes, causing poor adhesion and a change of electrical properties of the varistor due to the loss of contact between electrodes and termination.

Keep the recommended down-cooling rate.

5.9 Standards

CECC 00802 IEC 60068-2-58 IEC 60068-2-20



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Symbols and terms

For ceramic transient voltage suppressors (CTVS)

Symbol	Term
C _{line,max}	Maximum capacitance per line
$\mathbf{C}_{line,min}$	Minimum capacitance per line
$\mathbf{C}_{line,typ}$	Typical capacitance per line
C _{max}	Maximum capacitance
C _{min}	Minimum capacitance
C _{nom}	Nominal capacitance
$\Delta \bm{C}_{\text{nom}}$	Tolerance of nominal capacitance
C _{typ}	Typical capacitance
$\mathbf{f}_{\text{cut-off,max}}$	Maximum cut-off frequency
$\mathbf{f}_{cut-off,min}$	Minimum cut-off frequency
$\mathbf{f}_{cut-off,typ}$	Typical cut-off frequency
f _{res,typ}	Typical resonance frequency
I	Current
I _{clamp}	Clamping current
I _{leak}	Leakage current
I _{leak,max}	Maximum leakage current
I _{leak,typ}	Typical leakage current
I _{PP}	Peak pulse current
I _{surge,max}	Maximum surge current (also termed peak current)
LCT	Lower category temperature
L _{typ}	Typical inductance
$\mathbf{P}_{\text{diss,max}}$	Maximum power dissipation
P _{PP}	Peak pulse power
R _{ins}	Insulation resistance
\mathbf{R}_{\min}	Minimum resistance
Rs	Resistance per line
$\mathbf{R}_{\mathrm{S,typ}}$	Typical resistance per line
T _A	Ambient temperature
T_{op}	Operating temperature
$T_{op,max}$	Maximum operating temperature
T _{stg}	Storage temperature



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Symbol	Term
t _r	Duration of equivalent rectangular wave
t _{resp}	Response time
t _{resp,max}	Maximum response time
UCT	Upper category temperature
V	Voltage
$V_{\text{BR,min}}$	Minimum breakdown voltage
$V_{\text{clamp,max}}$	Maximum clamping voltage
$V_{\text{DC,max}}$	Maximum DC operating voltage (also termed working voltage)
$V_{\text{ESD,air}}$	Air discharge ESD capability
$V_{\text{ESD,contact}}$	Contact discharge ESD capability
V_{jump}	Maximum jump-start voltage
$V_{\text{RMS,max}}$	Maximum AC operating voltage, root-mean-square value
V_{v}	Varistor voltage (also termed breakdown voltage)
V_{LD}	Maximum load dump voltage
V _{leak}	Measurement voltage for leakage current
$V_{\text{V,min}}$	Minimum varistor voltage
$V_{v,\text{max}}$	Maximum varistor voltage
ΔV_{v}	Tolerance of varistor voltage
W_{LD}	Maximum load dump energy
W _{max}	Maximum energy absorption (also termed transient energy)
$lpha_{typ}$	Typical insertion loss
tan δ	Dissipation factor
е	Lead spacing
≪*≫	Maximum possible application conditions

All dimensions are given in mm.

The commas used in numerical values denote decimal points.



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Cautions and warnings

General

Some parts of this publication contain statements about the suitability of our ceramic transient voltage suppressor (CTVS) components (multilayer varistors (MLVs)), CeraDiodes, ESD/EMI filters, leaded transient voltage/ RFI suppressors (SHCV types)) for certain areas of application, including recommendations about incorporation/design-in of these products into customer applications. The statements are based on our knowledge of typical requirements often made of our CTVS devices in the particular areas. We nevertheless expressly point out that such statements cannot be regarded as binding statements about the suitability of our CTVS components for a particular customer application. As a rule, EPCOS is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always incumbent on the customer to check and decide whether the CTVS devices with the properties described in the product specification are suitable for use in a particular customer application.

- Do not use EPCOS CTVS components for purposes not identified in our specifications, application notes and data books.
- Ensure the suitability of a CTVS in particular by testing it for reliability during design-in. Always evaluate a CTVS component under worst-case conditions.
- Pay special attention to the reliability of CTVS devices intended for use in safety-critical applications (e.g. medical equipment, automotive, spacecraft, nuclear power plant).

Design notes

- Always connect a CTVS in parallel with the electronic circuit to be protected.
- Consider maximum rated power dissipation if a CTVS has insufficient time to cool down between a number of pulses occurring within a specified isolated time period. Ensure that electrical characteristics do not degrade.
- Consider derating at higher operating temperatures. Choose the highest voltage class compatible with derating at higher temperatures.
- Surge currents beyond specified values will puncture a CTVS. In extreme cases a CTVS will burst.
- If steep surge current edges are to be expected, make sure your design is as low-inductance as possible.
- In some cases the malfunctioning of passive electronic components or failure before the end of their service life cannot be completely ruled out in the current state of the art, even if they are operated as specified. In applications requiring a very high level of operational safety and especially when the malfunction or failure of a passive electronic component could endanger human life or health (e.g. in accident prevention, life-saving systems, or automotive battery line applications such as clamp 30), ensure by suitable design of the application or other measures (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of such a malfunction or failure. Only use CTVS components from the automotive series in safety-relevant applications.



Surge protection series

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Specified values only apply to CTVS components that have not been subject to prior electrical, mechanical or thermal damage. The use of CTVS devices in line-to-ground applications is therefore not advisable, and it is only allowed together with safety countermeasures like thermal fuses.

Storage

- Only store CTVS in their original packaging. Do not open the package prior to processing.
- Storage conditions in original packaging: temperature -25 to +45°C, relative humidity ≤75% annual average, maximum 95%, dew precipitation is inadmissible.
- Do not store CTVS devices where they are exposed to heat or direct sunlight. Otherwise the packaging material may be deformed or CTVS may stick together, causing problems during mounting.
- Avoid contamination of the CTVS surface during storage, handling and processing.
- Avoid storing CTVS devices in harmful environments where they are exposed to corrosive gases for example (SO_x, CI).
- Use CTVS as soon as possible after opening factory seals such as polyvinyl-sealed packages.
- Solder CTVS components after shipment from EPCOS within the time specified:
 - CTVS with Ni barrier termination, 12 months
 - CTVS with AgPt termination, 6 months
 - SHCV, 24 months

Handling

- Do not drop CTVS components and allow them to be chipped.
- Do not touch CTVS with your bare hands gloves are recommended.
- Avoid contamination of the CTVS surface during handling.
- Washing processes may damage the product due to the possible static or cyclic mechanical loads (e.g. ultrasonic cleaning). They may cause cracks to develop on the product and its parts, which might lead to reduced reliability or lifetime.

Mounting

- When CTVS devices are encapsulated with sealing material or overmolded with plastic material, electrical characteristics might be degraded and the life time reduced.
- Make sure an electrode is not scratched before, during or after the mounting process.
- Make sure contacts and housings used for assembly with CTVS components are clean before mounting.
- The surface temperature of an operating CTVS can be higher. Ensure that adjacent components are placed at a sufficient distance from a CTVS to allow proper cooling.
- Avoid contamination of the CTVS surface during processing.



Surge protection series

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Soldering

- Complete removal of flux is recommended to avoid surface contamination that can result in an instable and/or high leakage current.
- Use resin-type or non-activated flux.
- Bear in mind that insufficient preheating may cause ceramic cracks.
- Rapid cooling by dipping in solvent is not recommended, otherwise a component may crack.

Operation

- Use CTVS only within the specified operating temperature range.
- Use CTVS only within specified voltage and current ranges.
- Environmental conditions must not harm a CTVS. Only use them in normal atmospheric conditions. Reducing the atmosphere (e.g. hydrogen or nitrogen atmosphere) is prohibited.
- Prevent a CTVS from contacting liquids and solvents. Make sure that no water enters a CTVS (e.g. through plug terminals).
- Avoid dewing and condensation.
- EPCOS CTVS components are mainly designed for encased applications. Under all circumstances avoid exposure to:
 - direct sunlight
 - rain or condensation
 - steam, saline spray
 - corrosive gases
 - atmosphere with reduced oxygen content
- EPCOS CTVS devices are not suitable for switching applications or voltage stabilization where static power dissipation is required.

This listing does not claim to be complete, but merely reflects the experience of EPCOS AG.

Display of ordering codes for EPCOS products

The ordering code for one and the same EPCOS product can be represented differently in data sheets, data books, other publications, on the EPCOS website, or in order-related documents such as shipping notes, order confirmations and product labels. **The varying representations of the ordering codes are due to different processes employed and do not affect the specifications of the respective products**. Detailed information can be found on the Internet under www.epcos.com/orderingcodes



The following applies to all products named in this publication:

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Important notes

- 7. Our manufacturing sites serving the automotive business apply the IATF 16949 standard. The IATF certifications confirm our compliance with requirements regarding the quality management system in the automotive industry. Referring to customer requirements and customer specific requirements ("CSR") TDK always has and will continue to have the policy of respecting individual agreements. Even if IATF 16949 may appear to support the acceptance of unilateral requirements, we hereby like to emphasize that only requirements mutually agreed upon can and will be implemented in our Quality Management System. For clarification purposes we like to point out that obligations from IATF 16949 shall only become legally binding if individually agreed upon.
- 8. The trade names EPCOS, CeraCharge, CeraDiode, CeraLink, CeraPad, CeraPlas, CSMP, CTVS, DeltaCap, DigiSiMic, ExoCore, FilterCap, FormFit, LeaXield, MiniBlue, MiniCell, MKD, MKK, MotorCap, PCC, PhaseCap, PhaseCube, PhaseMod, PhiCap, PowerHap, PQSine, PQvar, SIFERRIT, SIFI, SIKOREL, SilverCap, SIMDAD, SiMic, SIMID, SineFormer, SIOV, ThermoFuse. WindCap are trademarks registered or pending in Europe and in other countries. Further information will be found on the Internet at www.tdk-electronics.tdk.com/trademarks.

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